

Standard Digital Isolators

DCM340C01

Quad - channel High speed Logic for Automotive equipment, Default Low output

1. Description

The DCM340C01 is a 16-pin SOIC Wide package default low-output, quad-channel high-speed digital isolator with the primary and secondary sides insulated and coupled by a magnetic coupling structure.

With a high isolation voltage of 5000 V_{rms}, it is suitable for control applications such as in-vehicle communication line insulation.

16pin SOIC Wide body

Weight: 0.426 g (typ.)

2. Applications

- Battery Control in Automotive Equipment
- Fuel Battery Control in Automotive Equipment
- Application for Electrical Vehicle
- **Date Converter Isolation** (Serial Peripheral Interface (SPI), etc.)

3. Features

Data rate 50 Mbps (Max)

Default Output Low

Number of channels 4 channels (Forward 4: Revers 0)

Suitable operating voltage 3.3 V or 5 V $5000 \; V_{rms}$ Isolation voltage

Common-Mode Transient Immunity: ±100 kV/µs (Typ)

Safety standards

AEC-Q100 (Grade1 qualified) UL: UL1577, File No. E519997

cUL: CSA Component Acceptance Service Notice No. E519997

Note: Typical test conditions: V_{DD1} =V_{DD2} = 3.3V or 5V, T_a = 25°C; unless otherwise specified.

4. Mechanical Parameters

Mechanical parameters Table 4.1

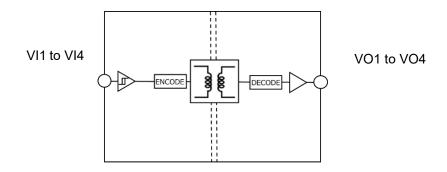
Characteristics	Symbol	unit	Unit
Creepage distances	CPG	7.6 (Min)	mm
Clearance distances	CLR	8 (Min)	mm
Distance Through the Insulation	DTI	17	μm

Start of commercial production 2024-12



5. Block Diagram

DCM340C01



Some of the functional blocks, circuits or constants labels in the block diagram may have been omitted or simplified for clarity.

Figure 5.1 Block Diagram



6. Pin Assignments

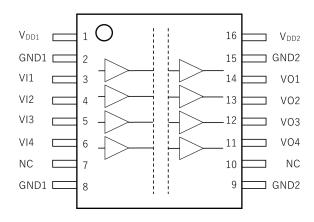


Figure 6.1 Pin Assignments (top view)

7. Pin Description

Table 7.1 Pin Description

Pin No	Pin name	I/O	Description
1	V_{DD1}	_	Power Supply, side 1
2	GND1	_	GND connection for VDD1 , side 1
3	VI1	IN	Logic Input, Channel 1
4	VI2	IN	Logic Input, Channel 2
5	VI3	IN	Logic Input, Channel 3
6	VI4	IN	Logic Input, Channel 4
7	NC	NC	Non - Connection
8	GND1	_	GND connection for VDD1, side 1
9	GND2	_	GND connection for VDD2, side 2
10	NC	NC	Non - Connection
11	VO4	OUT	Logic Output, Channel 4
12	VO3	OUT	Logic Output, Channel 3
13	VO2	OUT	Logic Output, Channel 2
14	VO1	OUT	Logic Output, Channel 1
15	GND2	_	GND connection for VDD2, side 2
16	V _{DD2}	_	Power Supply, side 2



8. Functional Description

8.1. Specifications of External Components

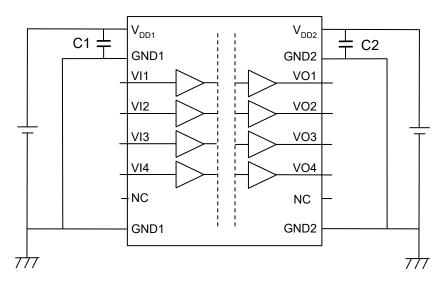


Figure 8.1 Pin Assignments (top view)

Table 8.1 External component specification (Note)

Component Name	Recommended Value	Pin	Description
C1	0.1µF	V _{DD1}	_
C2	0.1µF	V_{DD2}	_

Note: Use Ceramic capacitors (C1,C2) with good high frequency characteristics.

Ceramic capacitors (C1,C2) should be connected between pin 1 (V_{DD1}) and pin 2 (GND1) for V_{DD1} and between pin 16 (V_{DD2}) and pin 15 (GND2) for V_{DD2}, and should

be the layout on the IC as close as possible (less than 10mm).

Otherwise, the IC may not switch properly.



8.2. Function Description

8.2.1. Truth table for each pin

Table 8.2 Truth table for each pin (Note)

	V _{DDI} Input side V _{DD}	V _{DDO} Output side V _{DD}	Input (VI1 to VI4)	Output (VO1 to VO4)	State Description
2	PU	PU	Low High	Low High	Normal Operation
3			OPEN	Low	Default mode
4	PU	PD	Undetermined	Undetermined	When V _{DDO} is unpowered, a channel output is undetermined.
5	PD	PU	Undetermined	Low	Default mode
6	PD	PD	Undetermined	Undetermined	When V _{DDO} is unpowered, a channel output is undetermined.

Note: PU = Powered Up $(V_{DD} \ge 2.25 \text{ V})$, PD = Powered Down $(V_{DD} \le 1.7 \text{ V})$

H = High Level , L = Low Level

Note: V_{DDI} = Input-side V_{DD} , V_{DDO} = Output-side V_{DD}



9. Absolute Maximum Ratings (Note)

Table 9.1 Absolute Maximum Ratings (Note)

 $(T_a = 25^{\circ}C \text{ unless otherwise specified})$

Characteristics	Condition	Symbol	Rating	Unit
Junction temperature	_	TJ	-40 to 150	°C
Storage temperature range	_	T _{stg}	-65 to 150	°C
Operation temperature range	_	T _{opr}	-40 to 125	°C
Soldering temperature	10s	T _{sol}	260	°C
Supply voltage (DC)	_	V _{DD1} ,V _{DD2}	-0.5 to 6.0	V
		VI(1 to 4)	-0.5 to V _{DDX} + 0.5 (Note 1)	V
		VO(1 to 4)	0.5 to V _{DDX} + 0.5 (Note 1)	٧
Output Current	_	lo	±15	mA
Isolation voltage	1min	BVs	5000	Vrms
Output current	V _{DD1} = V _{DD2} = 5.5 V, Tj = 150 °C, Ta = 25 °C	I _{S1}	284	mA
	V _{DD1} = V _{DD2} = 3.6 V, Tj = 150 °C, Ta = 25 °C	I _{S2}	434	mA
Power dissipation	Tj = 150 °C, Ta = 25 °C	P _{d Max}	1562	mW

Note: The absolute maximum ratings of a semiconductor device are a set of specified parameter values, which must not be exceeded during operation, even for an instant.

If any of these rating would be exceeded during operation, the device electrical characteristics may be irreparably altered, and the reliability and lifetime of the device can no longer be guaranteed. Moreover, these operations with exceeded ratings may cause break down, damage, and/or degradation to any other equipment. Applications using the device should be designed such that each maximum rating will never be exceeded in any operating conditions.

Before using, creating, and/or producing designs, refer to and comply with the precautions and conditions set forth in this document.

Note 1: Maximum voltage must not exceed 6V.



9.1. Power Dissipation

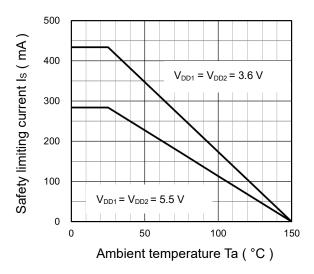


Figure 9.1 Thermal derating curve for safety limiting current

10. Recommended operating conditions

Table 10.1 Recommended Operating Ranges (Note)

Characteristics	Symbol	Min	Max	Unit
Operation voltage	V_{DD1} , V_{DD2}	3.0	5.5	V
Junction temperature	TJ	-40	150	°C
Operating temperature	T _{opr}	-40	125	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.



11. Electrical Characteristics

11.1 DC characteristics - 5V Supply

Table 11.1 DC characteristics – 5V Supply (Note)

(V_{DD1} = V_{DD2} =4.5 V to 5.5 V over recommended operating conditions unless otherwise noted)

Characteristics	Symbol	Test condition	Min	Тур	Max	Unit
V _{DD} Under Voltage	VDD _{xUV+}	Positive VDDx Threshold	_	2.1	2.25	
Lockout threshold	VDD _{xUV} -	Negative VDDx Threshold	1.7	1.9	_	V
Voltage	VDD _{xUVH}	VDDx Hysteresis	0.1	0.2	_	
Logic High-level	Mari	V _{Ix} = High , I _{OH} = -20 μA	V _{DDO} - 0.1	V _{DDO}	_	V
output voltage	Vон	V _{Ix} = High , I _{OH} = -4 mA	V _{DDO} - 0.4	V _{DDO} -0.2	_	V
Logic Low-level	V	V _{Ix} = High , I _{OL} = 20 μA	_	0	0.1	V
output voltage	V _{OL}	V _{Ix} = High , I _{OL} = 4 mA	_	0.2	0.4	V
Output Impedance	Z _O	_	_	50	_	Ω
Logic High-level input Threshold voltage	V _{IH}	_	0.7 x V _{DDI}	_	_	V
Logic Low-level input Threshold voltage	V _{IL}	_	_	_	0.3 x V _{DDI}	V
Logic Input threshold voltage hysteresis	V _H YS	_	_	0.37	_	٧
Input current	l _l	$V_I = V_{DDI}$ or 0 V			±10	μA

Note: $V_{DDI} = Input\text{-side}V_{DD}$, $V_{DDO} = Output\text{-side}V_{DD}$



11.2 Switching Characteristics – 5 V Supply

Table 11.2 Switching Characteristics - 5 V Supply

 $(V_{DD1} = V_{DD2} = 4.5 \text{ V to } 5.5 \text{ V over recommended operating conditions unless otherwise noted})$

Chara	cteristics	Symbol	Test condition	Min	Тур	Max	Unit
Data Rate		t _{bps}	_	DC	_	50	Mbps
Propagatio	n Delay	t _{PHL} , t _{PLH}	50 kHz, Duty = 50 %, C _L = 15 pF	_	10.9	18.4	ns
Pulse Widtl	n Distortion	PWD	tphl — tplh	_	0.8	5.1	ns
	n Delay Skew ny two units)	tpsk	(Note1)	_	_	13.0	ns
Channel Matching	Codirectional	t _{skCD}	_	_	_	4.4	ns
Output sigr	nal	t _r	10% to 90%	_	0.9	_	ns
Output sigr	nal	t _f	90% to 10%	_	0.9	_	ns
Common-N Transient Ir		CMTI	V _I = V _{DDI} or 0 V, V _{CM} = 1500 V	_	100	_	kV/µs

Note1: The Propagation delay skew, t_{PSK}, is equal to the magnitude of the difference in propagation delay.

That will be seen between units at the same given conditions (supply voltage, input current, temperature, etc.).

11.3 Supply Current Characteristics – 5 V Supply

Table 11.3 Supply Current Characteristics - 5 V Supply

 $(V_{DD1} = V_{DD2} = 4.5 \text{ V to } 5.5 \text{ V over recommended operating conditions unless otherwise noted})$

C	Characteristics			Test condition	Min	Тур	Max	Unit
		Drimonyaida	I _{DDQ1(0)5}	V _I = Low	_	2.1	3.0	mA
DC Supply	Current	Primary side	I _{DDQ1(1)5}	V _I = High	_	19.6	28.1	IIIA
DC Supply	Current	Secondary side	I _{DDQ2(0)5}	V _I = Low	_	5.0	7.3	mA
			$I_{DDQ2(1)5}$ $V_I = High$		_	5.3	7.6	MA
	t _{bps} =	Primary side	I _{DD1(1)5}	f _{CLK} = 500 kHz, Duty = 50 %	_	11.2	17.5	mA
	1 Mbps	Secondary side	I _{DD2(1)5}	square wave, $C_L = 15 pF$	_	5.4	8.3	IIIA
Supply Current	t _{bps} =	Primary side	I _{DD1(25)5}	f _{CLK} = 12.5 MHz, Duty = 50 %	_	11.0	17.1	mA
(AC signal) 25 Mbps t _{bps} =	Secondary side	I _{DD2(25)5}	square wave, $C_L = 15 pF$	_	9.8	14.7	IIIA	
	t _{bps} =	Primary side	I _{DD1(50)5}	f _{CLK} = 25 MHz, Duty = 50 %	_	11.5	17.5	mA
	50 Mbps	Secondary side	I _{DD2(50)5}	square wave, C _L = 15 pF	_	14.9	22.2	IIIA



11.4 DC characteristics – 3.3 V Supply

Table 11.4 DC characteristics – 3.3V Supply (Note)

 $(V_{DD1} = V_{DD2} = 3.0 \text{ V} \text{ to } 3.6 \text{ V} \text{ over recommended operating conditions unless otherwise noted})$

Characteristics	Symbol	Test condition	Min	Тур	Max	Unit
V _{DD} Under Voltage	VDD _{xUV+}	Positive VDDx Threshold	_	2.1	2.25	
Lockout threshold	VDD _{xUV} -	Negative VDDx Threshold	1.7	1.9	_	V
Voltage	VDD _{xUVH}	VDDx Hysteresis	0.1	0.2	_	
Logic High-level	V	V _{Ix} = High , I _{OH} = -20 μA	VDDO - 0.1	VDDO	_	V
output voltage	Voн	V _{Ix} = High , I _{OH} = -4 mA	V _{DDO} - 0.4	V _{DDO} -0.2	_	V
Logic Low-level	V/	V _{Ix} = High , I _{OL} = -20 μA	_	0	0.1	V
output voltage	Vol	V _{Ix} = High , I _{OL} = 4 mA	_	0.2	0.4	V
Output Impedance	Zo	_	_	50	_	Ω
Logic High-level input Threshold voltage	ViH	_	0.7 x V _{DDI}	_	_	٧
Logic Low-level input Threshold voltage	VIL	_	_	_	0.3 x VDDI	V
Logic Input threshold voltage hysteresis	V _H YS	_	_	0.32	_	٧
Input current	l _l	V _I = V _{DDI} or 0 V	_	_	±10	μΑ

Note: $V_{DDI} = Input\text{-side}V_{DD}$, $V_{DDO} = Output\text{-side}V_{DD}$



11.5 Switching Characteristics - 3.3 V Supply

Table 11.5 Switching Characteristics - 3.3 V Supply

 $(V_{DD1} = V_{DD2} = 3.0 \text{ V} \text{ to } 3.6 \text{ V} \text{ over recommended operating conditions unless otherwise noted})$

Chara	Characteristics		Test condition	Min	Тур	Max	Unit
Data Rate		t _{bps}	_	DC	_	50	Mbps
Propagatio	n Delay	t _{PHL} , t _{PLH}	50 kHz, Duty = 50 %, C _L = 15 pF	_	11.6	19.2	ns
Pulse Widt	h Distortion	PWD	tphl — tplh	_	0.8	5.1	ns
	n Delay Skew ny two units)	tpsk	(Note1)	_	_	13.0	ns
Channel Matching	Codirectional	t _{skCD}	_		_	4.4	ns
Output signates of the contract of the contrac	nal	t _r	10% to 90%	_	0.9	_	ns
Output sign	nal	t _f	90% to 10%	_	0.9	_	ns
Common-N Transient II		CMTI	V _I = V _{DDI} or 0 V, V _{CM} = 1500 V	_	100	_	kV/µs

Note1: The Propagation delay skew, t_{PSK}, is equal to the magnitude of the difference in propagation delay.

That will be seen between units at the same given conditions (supply voltage, input current, temperature, etc.).

11.6 Supply Current Characteristics – 3.3 V Supply

Table 11.6 Supply Current Characteristics – 3.3 V Supply

 $(V_{DD1} = V_{DD2} = 3.0 \text{ V} \text{ to } 3.6 \text{ V} \text{ over recommended operating conditions unless otherwise noted})$

C	Characteristics		Symbol	Test condition	Min	Тур	Max	Unit
		Drimonyaida	I _{DDQ1(0)5}	V _I = Low	_	2.0	2.9	mA
DC Cumply	Cummant	Primary side	I _{DDQ1(1)5}	V _I = High	_	19.4	27.7	mA
DC Supply	Current	Secondary side	I _{DDQ2(0)5}	V _I = Low	_	4.9	7.1	mΛ
			I _{DDQ2(1)5} V _I = High		_	5.2	7.4	mA
	t _{bps} =	Primary side	I _{DD1(1)5}	f _{CLK} = 500 kHz, Duty = 50 %	_	11.0	16.7	m A
	1 Mbps	Secondary side	I _{DD2(1)5}	square wave, C _L = 15 pF	_	5.2	7.8	mA
Supply	t _{bps} =	Primary side	I _{DD1(25)5}	f _{CLK} = 12.5 MHz, Duty = 50 %	_	10.6	16.0	т Л
(AC signal)	Current 25 Mbps	Secondary side	I _{DD2(25)5}	square wave, $C_L = 15 pF$	_	8.2	12.4	mA
t _{bps} =	t _{bps} =	Primary side	I _{DD1(50)5}	f _{CLK} = 25 MHz, Duty = 50 %	_	10.9	16.2	т Л
	50 Mbps	Secondary side	I _{DD2(50)5}	square wave, C _L = 15 pF	_	11.0	18.0	mA



12. Characteristic Chart (Note)

12.1 Supply Current vs Data rate

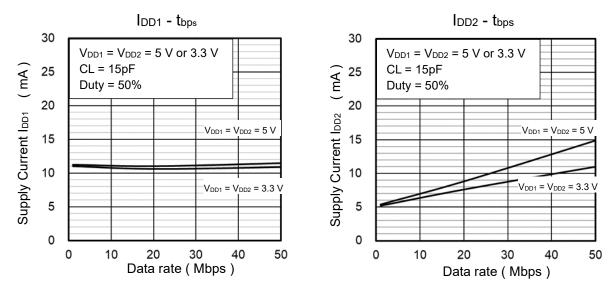


Figure12.1 Supply Current - Data rate

12.2 Output Voltage vs Output Current

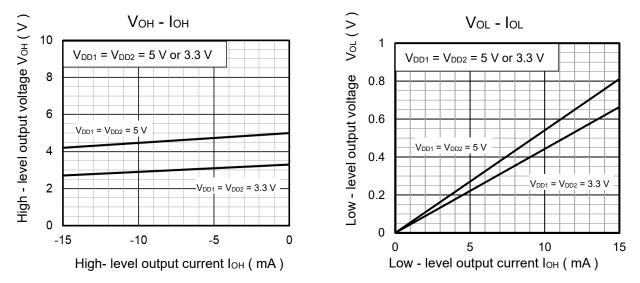


Figure 12.2 Output Voltage - Output Current

Note: The following characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



12.3 Propagation Delay Time vs Ambient Temperature

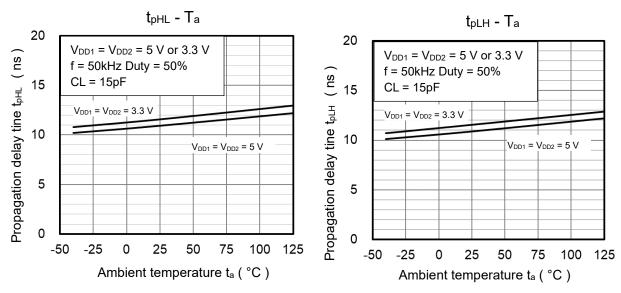
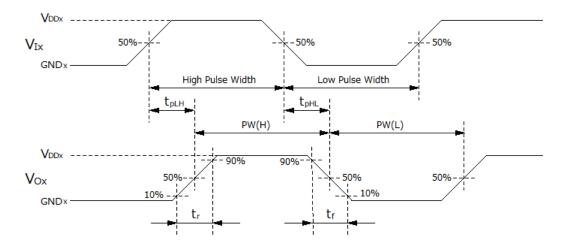


Figure 12.3 Propagation Delay Time vs Ambient Temperature



Switching Waveforms Figure12.4

The following characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



13. Package Information

Table 13.1 Insulation Related Specifications (Note)

Parameters	Symbol	DCM340C01	Unit
Minimum clearance	CLR	8.0	mm
Minimum creepage distance	CPG	7.6	mm
Minimum insulation thickness	DTI	17	μm
Comparative tracking index	CTI	550	V

Note: If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. (e.g., at a standard distance between soldering eye centers of 7.5 mm). If this is not permissible, the user shall take suitable measures.

Note: This photocoupler is suitable for safe electrical isolation only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.

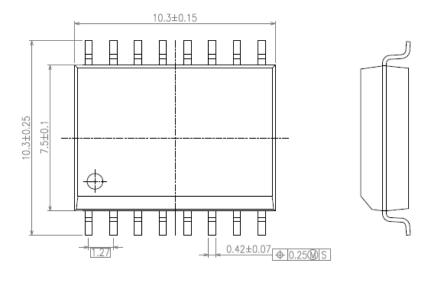


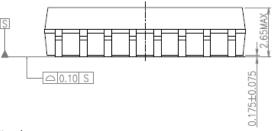
14. Package Information

14.1 Package dimensions

16pin SOIC Wide body (P-SOP16-0811-1.27-002)

Unit: mm





Weight: 0.426 g (typ.)

Figure 14.1 Package Dimensions



Land Pattern Dimensions for Reference only

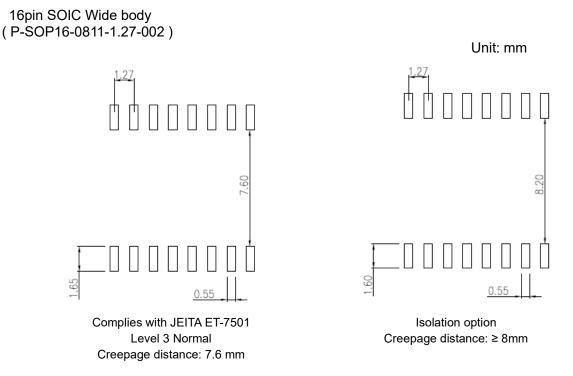


Figure 14.2 Land Pattern Dimensions for Reference only

Notes.

- Unless otherwise indicated, dimensions are given in millimeters.
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